NPN PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

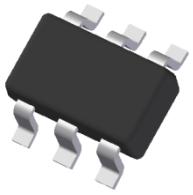
Part Number	R1 (NOM)	R2 (NOM)
DDC124EU	22kΩ	22kΩ
DDC144EU	47kΩ	47kΩ
DDC114YU	10kΩ	47kΩ
DDC123JU	2.2kΩ	47kΩ
DDC114EU	10kΩ	10kΩ
DDC143ZU	4.7kΩ	47kΩ
DDC115EU	100kΩ	100kΩ

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.006 grams (Approximate)

Part Number	R1 Only
DDC113TU	1kΩ
DDC143TU	4.7kΩ
DDC114TU	10kΩ

SOT363



Top View

Device Schematic

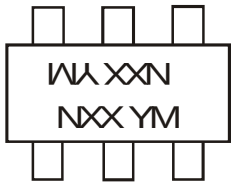
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DDC124EU-7-F	AEC-Q101	N17	7	8	3,000
DDC124EUQ-7-F	Automotive	N17	7	8	3,000
DDC144EU-7-F	AEC-Q101	N20	7	8	3,000
DDC114YU-7-F	AEC-Q101	N14	7	8	3,000
DDC114YUQ-7-F	Automotive	N14	7	8	3,000
DDC114YUQ-13-F	Automotive	N14	13	8	10,000
DDC123JU-7-F	AEC-Q101	N06	7	8	3,000
DDC114EU-7-F	AEC-Q101	N13	7	8	3,000
DDC114EUQ-7-F	Automotive	N13	7	8	3,000
DDC114EUQ-13-F	Automotive	N13	13	8	10,000
DDC113TU-7-F	AEC-Q101	N01	7	8	3,000
DDC143TU-7-F	AEC-Q101	N07	7	8	3,000
DDC114TU-7-F	AEC-Q101	N12	7	8	3,000
DDC114TUQ-7-F	Automotive	N12	7	8	3,000
DDC143ZU-7-F	AEC-Q101	N03	7	8	3,000
DDC115EU-7-F	AEC-Q101	N02	7	8	3,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT363



NXX = Product Type Marking Code
See Page 1 Diagrams
YM = Date Code Marking
Y = Year (ex: E = 2017)
M = Month (ex: 9 = September)

Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017	2018	2019	2020
Code	X	Y	Z	A	B	C	D	E	F	G	H

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage, <Pin: (6) to (1) and (3) to (4)>		V_{CC}	50	V
Input Voltage, <Pin: (2) to (1) and (5) to (4)>	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC113TU DDC143TU DDC114TU DDC143ZU DDC115EU	V_{IN}	-10 to +40 -10 to +40 -6 to +40 -5 to +12 -10 to +40 -5V max -5V max -5V max -5 to +30 -10 to +40	V
Output Current	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC113TU DDC143TU DDC114TU DDC143ZU DDC115EU	I_O	30 30 70 100 50 100 100 100 100 20	mA
Output Current		$I_{C(MAX)}$	100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 6 & 7)	P_D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes: 6. Mounted on FR4 PC Board with minimum recommended pad layout.
7. 150mW per element must not be exceeded.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

For R1 only devices: DDC113TU & DDC143TU & DDC114TU

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	50	—	—	V	I_C = 50μA
Collector-Emitter Breakdown Voltage	BV_{CEO}	50	—	—	V	I_C = 1mA
Emitter-Base Breakdown Voltage	BV_{EBO}	5	—	—	V	I_E = 50μA
Collector Cutoff Current	I_{CBO}	—	—	0.5	μA	V_{CB} = 50V
Emitter Cutoff Current	I_{EBO}	—	—	0.5	μA	V_{EB} = 4V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	—	0.3	V	I_C/I_B = 2.5mA / 0.25mA DDC143TU I_C/I_B = 1mA / 0.1mA DDC114TU I_C/I_B = 10mA / 1mA DDC113TU
DC Current Transfer Ratio	h_{FE}	100	250	600	—	I_C = 1mA, V_{CE} = 5V
Input Resistor (R_1) Tolerance	ΔR_1	-30	—	+30	%	—
Gain-Bandwidth Product	f_T	—	250	—	MHz	V_{CE} = 10V, I_E = -5mA, f = 100MHz

For R1, R2 devices: DDC124EU& DDC144EU& DDC114YU& DDC123JU& DDC114EU& DDC143ZU& DDC115EU

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC143ZU DDC115EU	$V_{L(OFF)}$	0.5 0.5 0.3 0.5 0.5 0.5 0.5	1.1 1.1 — — 1.1 — —	—	V	V_{CC} = 5V, I_O = 100μA
	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC143ZU DDC115EU	$V_{L(ON)}$	—	1.9 1.9 — — 1.9 — —	3.0 3.0 1.4 1.1 3.0 1.3 3		V_O = 0.3V, I_O = 5mA V_O = 0.3V, I_O = 2mA V_O = 0.3V, I_O = 1mA V_O = 0.3V, I_O = 5mA V_O = 0.3V, I_O = 10mA V_O = 0.3V, I_O = 5mA V_O = 0.3V, I_O = 1mA
Output Voltage	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC143ZU DDC115EU	$V_{O(ON)}$	—	0.1	0.3	V	I_O/I_L = 10mA / 0.5mA I_O/I_L = 10mA / 0.5mA I_O/I_L = 5mA / 0.25mA I_O/I_L = 5mA / 0.25mA I_O/I_L = 10mA / 0.5mA I_O/I_L = 5mA / 0.25mA I_O/I_L = 10mA / 0.5mA
Input Current	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC143ZU DDC115EU	I_L	—	—	0.36 0.18 0.88 3.6 0.88 1.8 0.15	mA	V_I = 5V
Output Current		$I_{O(OFF)}$	—	—	0.5	μA	V_{CC} = 50V, V_I = 0V
DC Current Gain	DDC124EU DDC144EU DDC114YU DDC114YUQ DDC123JU DDC114EU DDC143ZU DDC115EU	G_L	56 68 68 80 80 30 80 82	—	—	—	V_O = 5V, I_O = 5mA V_O = 5V, I_O = 5mA V_O = 5V, I_O = 10mA V_O = 5V, I_O = 5mA V_O = 5V, I_O = 10mA V_O = 5V, I_O = 5mA V_O = 5V, I_O = 10mA V_O = 5V, I_O = 5mA
Input Resistor (R_1) Tolerance		ΔR_1	-30	—	+30	%	—
Resistance Ratio Tolerance		$\Delta(R_2/R_1)$	-20	—	+20	%	—
Gain-Bandwidth Product		f_T	—	250	—	MHz	V_{CE} = 10V, I_E = 5mA, f = 100MHz

Typical Curves – DDC123JU (@T_A = +25°C, unless otherwise specified.)

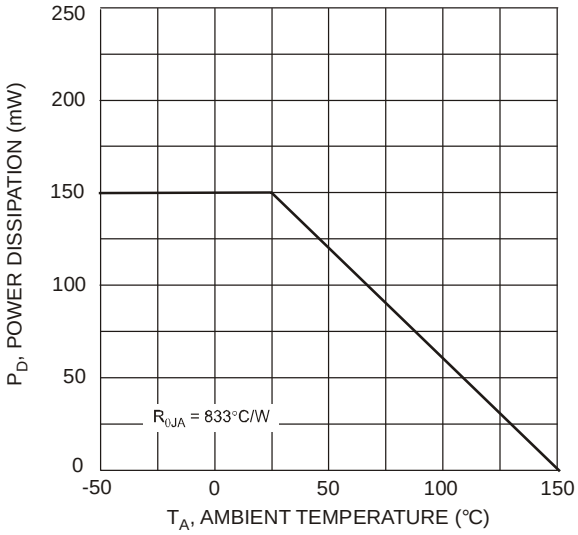


Fig. 1 Derating Curve

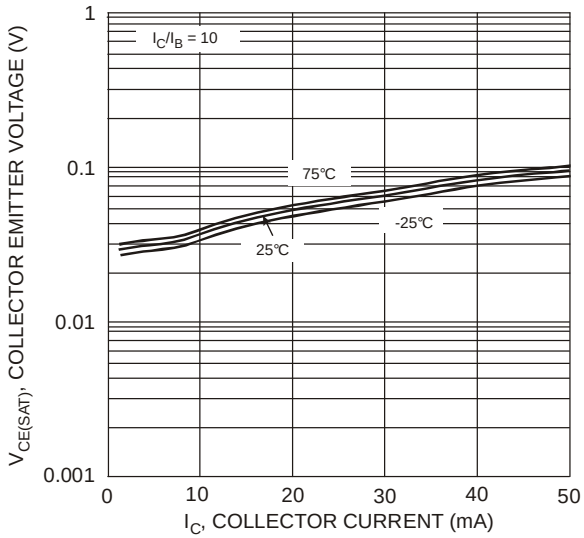


Fig. 2 $V_{CE(SAT)}$ vs. I_C

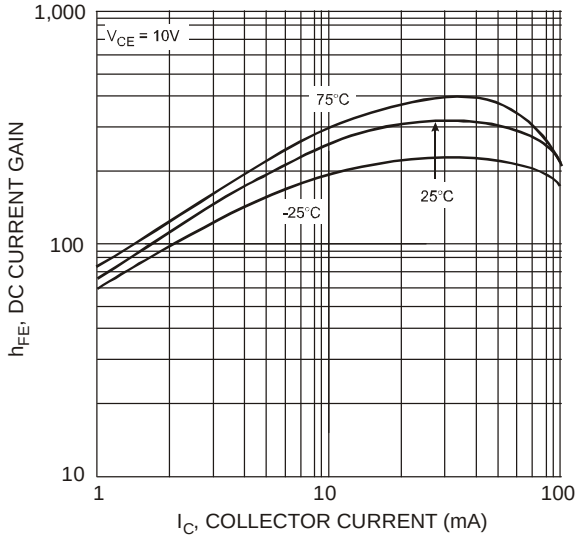


Fig. 3 DC Current Gain

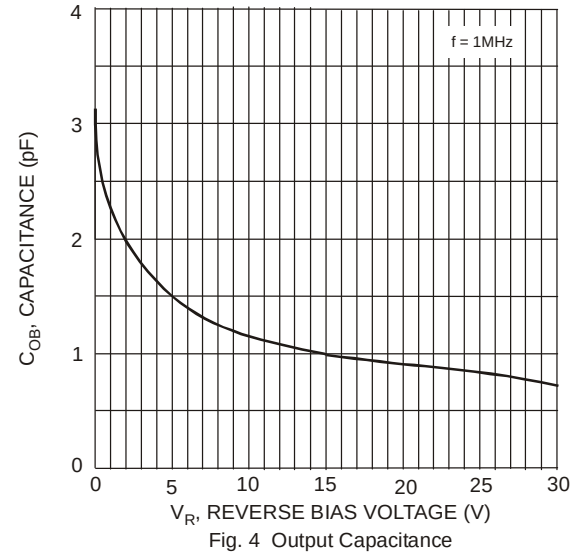


Fig. 4 Output Capacitance

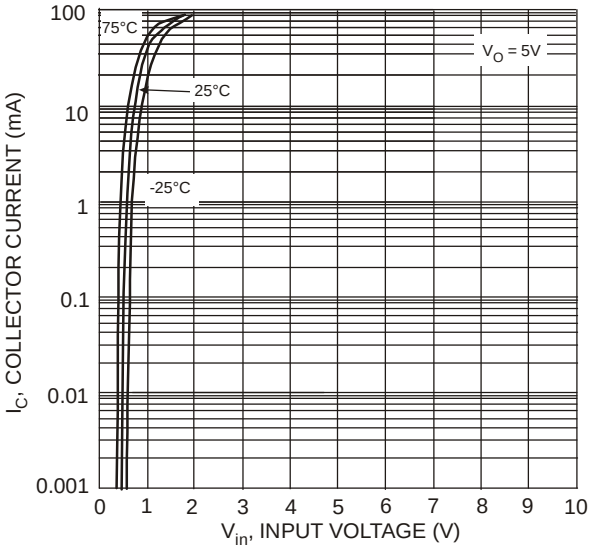


Fig. 5 Collector Current vs. Input Voltage

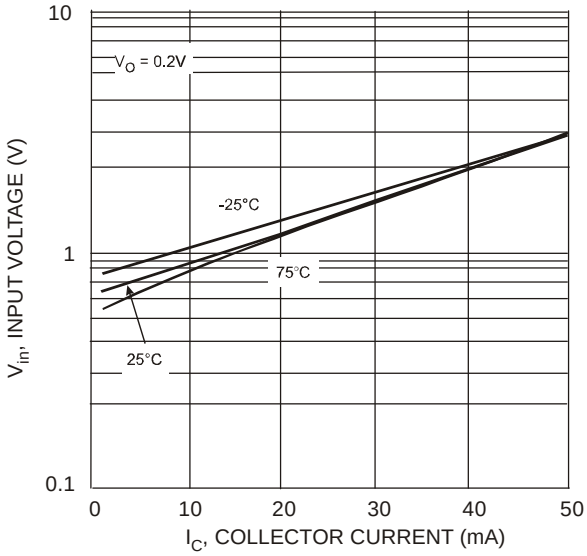


Fig. 6 Input Voltage vs. Collector Current

Typical Curves – DDC114YU (@T_A = +25°C, unless otherwise specified.)

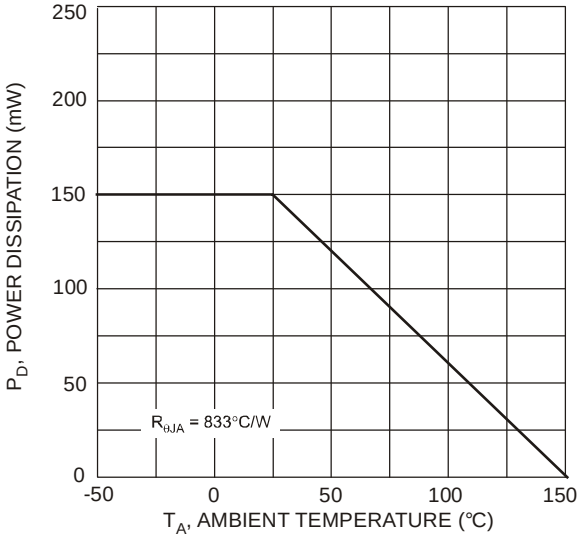


Fig. 1 Derating Curve

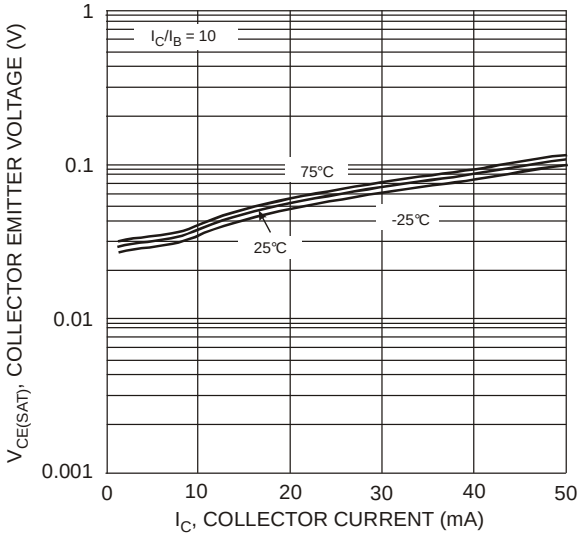


Fig. 2 $V_{CE(SAT)}$ vs. I_C

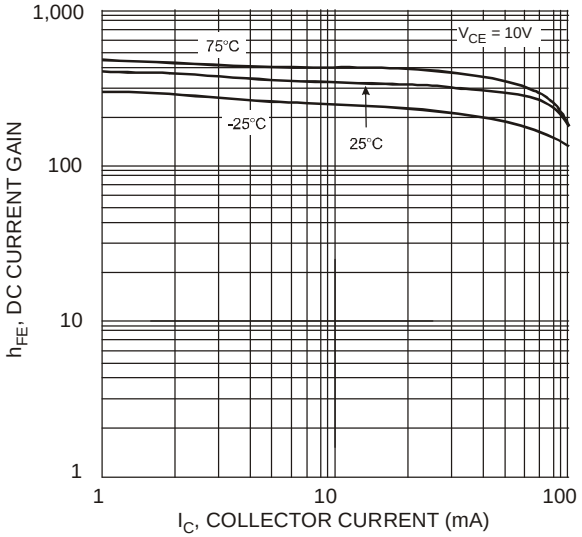


Fig. 3 DC Current Gain

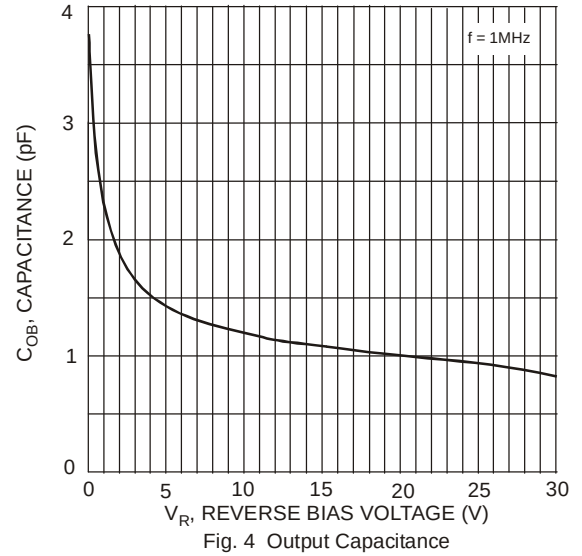


Fig. 4 Output Capacitance

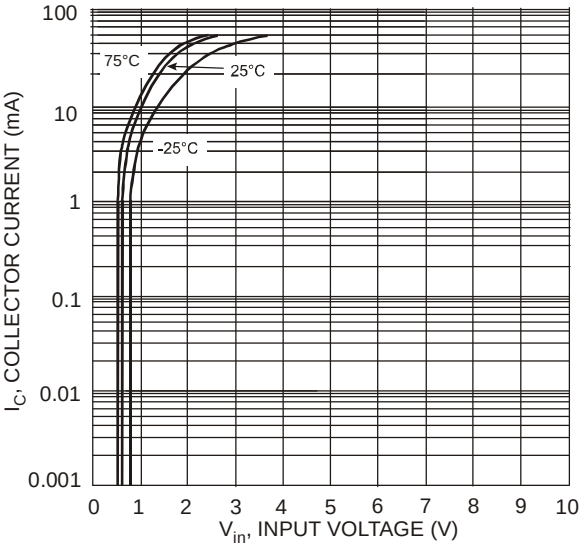


Fig. 5 Collector Current vs. Input Voltage

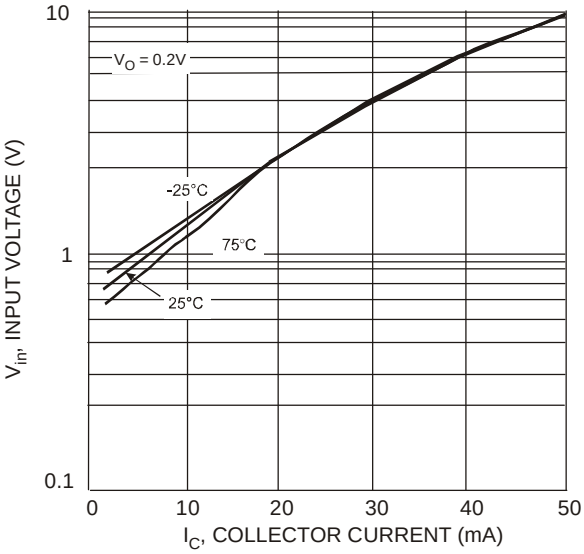


Fig. 6 Input Voltage vs. Collector Current

Typical Curves – DDC124EU (@T_A = +25°C, unless otherwise specified.)

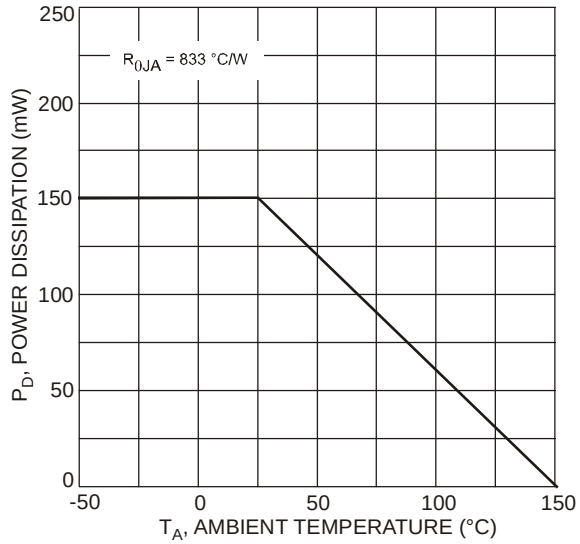


Fig. 1 Power Dissipation vs. Ambient Temeprature

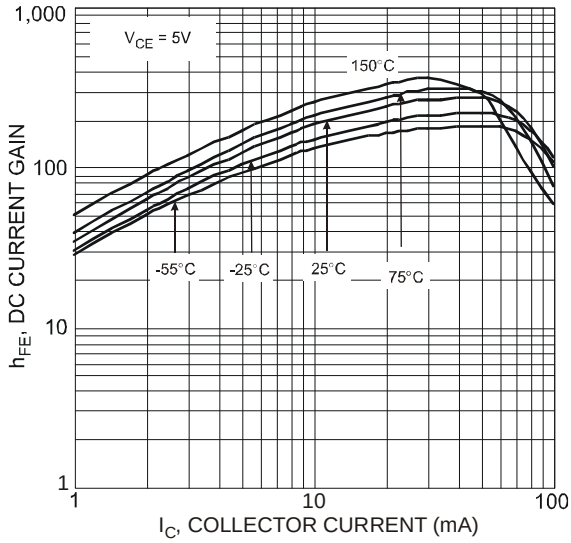


Fig. 2 Typical DC Current Gain vs. Collector Current

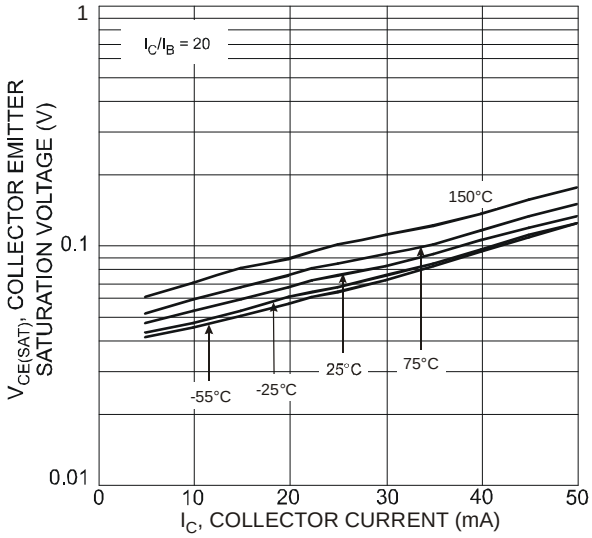


Fig. 3 Collector Emitter Saturation Voltage vs. Collector Current

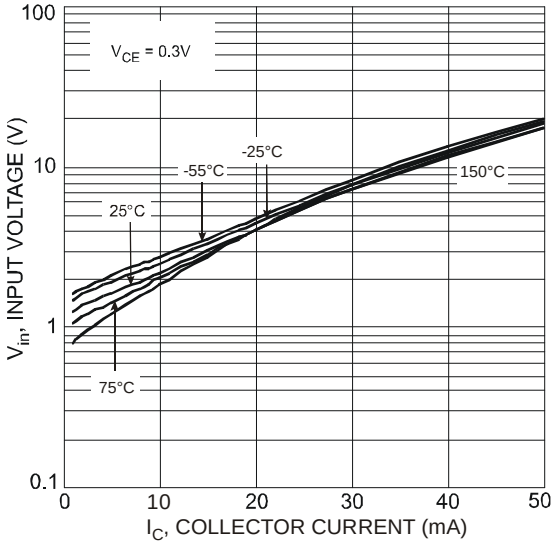
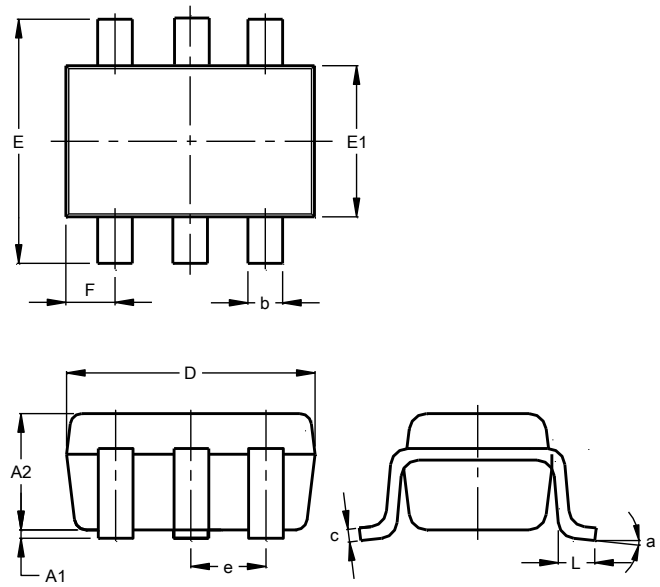


Fig. 4 Input Voltage vs. Collector Current

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363

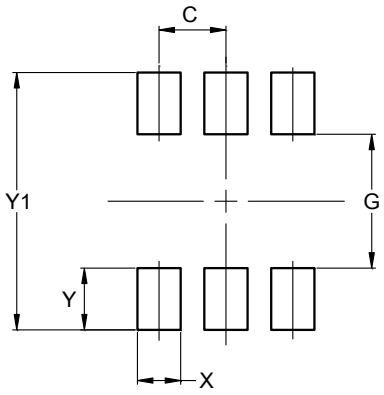


SOT363			
Dim	**Min**	**Max**	**Typ**
A1	0.00	0.10	0.05
A2	0.90	1.00	1.00
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.420
Y	0.600
Y1	2.500

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2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

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